2N5457, 2N5458

JFETs - General Purpose

N-Channel - Depletion

N-Channel Junction Field Effect Transistors, depletion mode (Type A) designed for audio and switching applications.

Features

- N-Channel for Higher Gain
- Drain and Source Interchangeable
- High AC Input Impedance
- High DC Input Resistance
- Low Transfer and Input Capacitance
- Low Cross-Modulation and Intermodulation Distortion
- Plastic Encapsulated Package
- Pb-Free Packages are Available*

MAXIMUM RATINGS

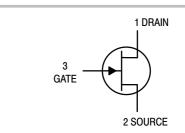
Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	25	Vdc
Drain - Gate Voltage	V_{DG}	25	Vdc
Reverse Gate - Source Voltage	V _{GSR}	-25	Vdc
Gate Current	IG	10	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	310 2.82	mW mW/°C
Operating Junction Temperature	TJ	135	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

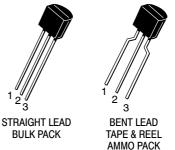
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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MARKING DIAGRAM

> 2N 545x AYWW■

TO-92 CASE 29 STYLE 5

2N545x = Device Code

x = 7 or 8

A = Assembly Location

Y = Year
WW = Work Week
■ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping
2N5457	TO-92	1000 Units/Box
2N5457G	TO-92 (Pb-Free)	1000 Units/Box
2N5458	TO-92	1000 Units/Box
2N5458G	TO-92 (Pb-Free)	1000 Units/Box

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

2N5457, 2N5458

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			1		I	L
Gate – Source Breakdown Voltage (I _G = −10 μAdc, V _{DS} = 0)		V _(BR) GSS	-25	_	_	Vdc
Gate Reverse Current $ (V_{GS} = -15 \text{ Vdc}, V_{DS} = 0) $ $ (V_{GS} = -15 \text{ Vdc}, V_{DS} = 0, T_A = 100^{\circ}\text{C}) $		l _{GSS}	- -	- -	- 1.0 -200	nAdc
Gate-Source Cutoff Voltage (V _{DS} = 15 Vdc, i _D = 10 nAdc)	2N5457 2N5458	V _{GS(off)}	-0.5 -1.0	- -	-6.0 -7.0	Vdc
Gate-Source Voltage $(V_{DS} = 15 \text{ Vdc}, i_D = 100 \mu\text{Adc})$ $(V_{DS} = 15 \text{ Vdc}, i_D = 200 \mu\text{Adc})$	2N5457 2N5458	V _{GS}	_ _	-2.5 -3.5	- -	Vdc
ON CHARACTERISTICS			•			
Zero-Gate-Voltage Drain Current (Note 1) (V _{DS} = 15 Vdc, V _{GS} = 0)	2N5457 2N5458	I _{DSS}	1.0 2.0	3.0 6.0	5.0 9.0	mAdc
DYNAMIC CHARACTERISTICS						
Forward Transfer Admittance (Note 1) (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1 kHz)	2N5457 2N5458	Y _{fs}	1000 1500	3000 4000	5000 5500	μmhos
Output Admittance Common Source (Note 1) (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1 kHz)		Y _{os}	-	10	50	μmhos
Input Capacitance (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1 kHz)		C _{iss}	-	4.5	7.0	pF
Reverse Transfer Capacitance (V _{DS} = 15 Vdc, V _{GS} = 0, f = 1 kHz)		C _{rss}	-	1.5	3.0	pF

Pulse Width ≤ 630 ms, Duty Cycle ≤ 10%.

TYPICAL CHARACTERISTICS For 2N5457 Only

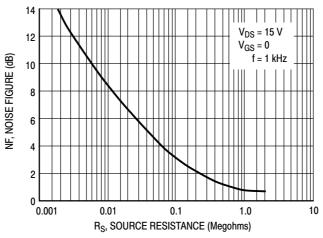


Figure 1. Noise Figure versus Source Resistance

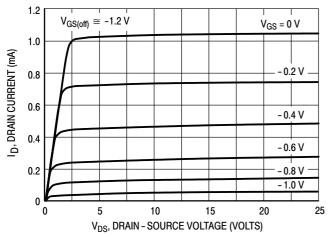


Figure 2. Typical Drain Characteristics

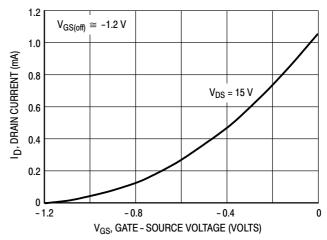


Figure 3. Common Source Transfer Characteristics

TYPICAL CHARACTERISTICS For 2N5457 Only

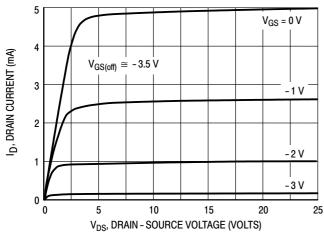


Figure 4. Typical Drain Characteristics

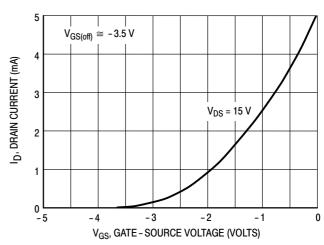


Figure 5. Common Source Transfer Characteristics

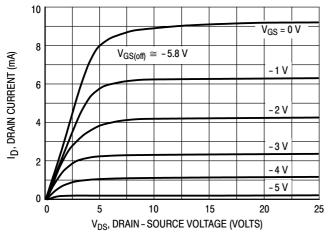


Figure 6. Typical Drain Characteristics

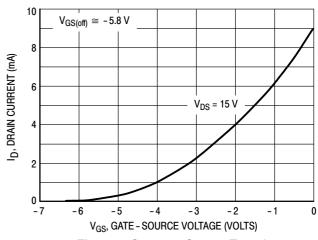
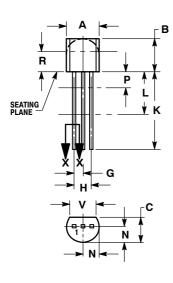


Figure 7. Common Source Transfer Characteristics

NOTE: Note: Graphical data is presented for dc conditions. Tabular data is given for pulsed conditions (Pulse Width = 630 ms, Duty Cycle = 10%). Under dc conditions, self heating in higher I_{DSS} units reduces I_{DSS} .

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AM**



STRAIGHT LEAD **BULK PACK**



BENT LEAD TAPE & REEL AMMO PACK



NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
V	0 135		3 43	

TYLE 5

PIN 1. DRAIN

- SOURCE
- 3 GATE

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS. CONTOUR OF PACKAGE BEYOND
- DIMENSION R IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM

	MILLIMETERS		
DIM	MIN MAX		
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93		
٧	3.43		

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